

## 1. General Description

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The EM74LVC2G04 is a dual inverter. Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in mixed 3.3 V and 5 V environments. Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times. This device is fully specified for partial power-down applications using IOFF. The IOFF circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

## 2. Features and Benefits

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- Wide supply voltage range from 1.65 V to 5.5 V
- Overvoltage tolerant inputs to 5.5 V
- High noise immunity
- $\pm 24$  mA output drive ( $V_{CC} = 3.0$  V)
- CMOS low power dissipation
- Direct interface with TTL levels
- IOFF circuitry provides partial Power-down mode operation
- Latch-up performance exceeds 100 mA
- Complies with JEDEC standard:
  - JESD8-7 (1.65 V to 1.95 V)
  - JESD8-5 (2.3 V to 2.7 V)
  - JESD8C (2.7 V to 3.6 V)
  - JESD36 (4.6 V to 5.5 V)
- ESD protection:
  - HBM ANSI/ESDA/JEDEC JS-001 Class 3B exceeds 8000 V
  - MM JESD22-A115C Class C exceeds 550 V
  - CDM ANSI/ESDA/JEDEC JS-002 Class C3 exceeds 2000 V
- Multiple package options

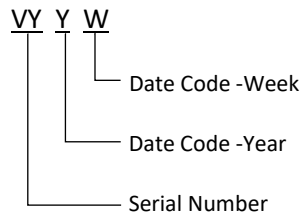
### 3. Ordering Information

**Table 1. Ordering information**

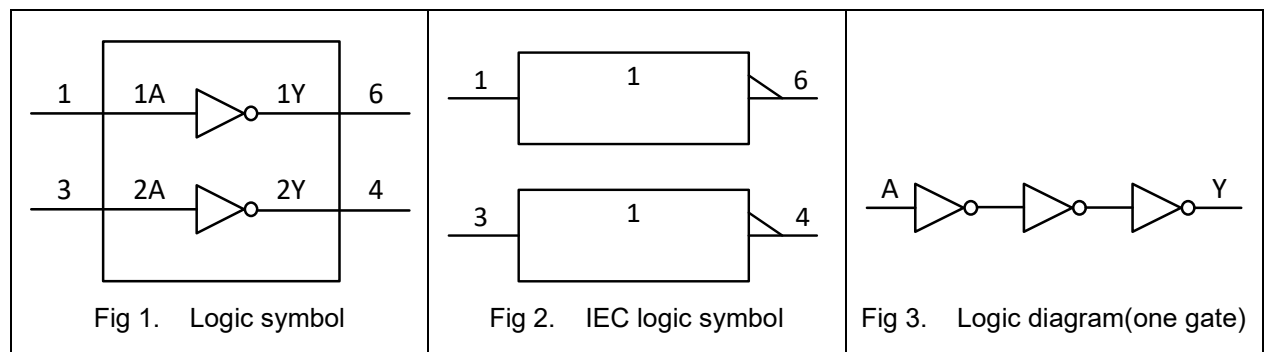
Type number	Topside marking	Package		Quantity
		Name	Description	
EM74LVC2G04GV	VYYW	SOT23-6L	SOT23 package, 6 pins 2.92 mm × 1.6 mm; 1.25 mm (Max) height	3000
EM74LVC2G04GW	VYYW	SOT363	SOT363 package, 6 pins 2.1 mm × 1.25 mm; 1.1 mm (Max) height	3000
EM74LVC2G04DRL	VYYW	SOT563	SOT563 package, 6 pins 1.6 mm × 1.2 mm; 0.6 mm (Max) height	3000
EM74LVC2G04GS	VY	DFN1x1-6L	DFN1×1 package, 6 pins 1 mm × 1 mm; 0.42 mm (Max) height	3000
EM74LVC2G04GM	VYYW	DFN1x1.45-6L	DFN1.45×1 package, 6 pins 1.45 mm × 1 mm; 0.6 mm (Max) height	3000

**MARKING INFORMATION**

NOTE: YW = Date Code.



### 4. Function Diagram



## 5. Pinning Information

### 5.1. Pin map

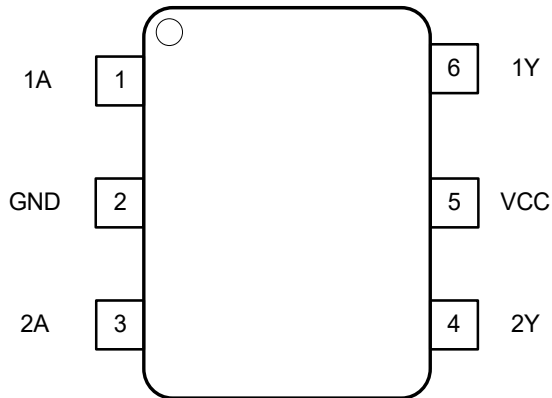


Fig 4. Top view pin configuration SOT23-6, SOT563 and SOT363

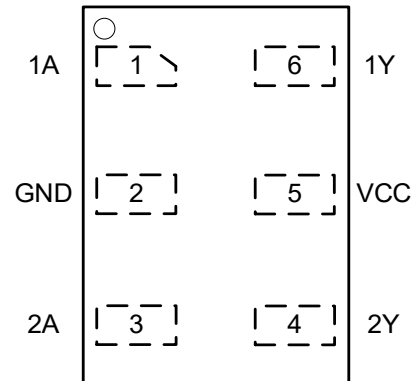


Fig 5. Top view pin configuration DFN6L

### 5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
1A	1	Data input
GND	2	Ground (0V)
2A	3	Data input
2Y	4	Data output
VCC	5	Supply voltage
1Y	6	Data output

## 6. Functional Description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level.

Input	Output
nA	nY
L	H
H	L

## 7. Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

**Table 4. Absolute Maximum Ratings**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND.

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	6.5	V
$I_{IK}$	input clamping current	$V_I < 0\text{ V}$	-50		mA
$V_I$	input voltage	[1]	-0.5	6.5	V
$I_{OK}$	output clamping current	$V_O > V_{CC}$ or $V_O < 0\text{ V}$		$\pm 50$	mA
$V_O$	output voltage	Active mode [1]	-0.5	$V_{CC} + 0.5$	V
		Power-down mode; $V_{CC} = 0\text{ V}$ [1]	-0.5	6.5	V
$I_O$	output current	$V_O = 0\text{ V}$ to $V_{CC}$		$\pm 50$	mA
$I_{CC}$	supply current			100	mA
$I_{GND}$	ground current		-100		mA
$P_{tot}$	total power dissipation	$T_{amb} = -40\text{ °C}$ to $+125\text{ °C}$		250	mW
$T_{stg}$	storage temperature		-65	150	°C

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## 8. Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. EnergyMath does not recommend exceeding them or designing to Absolute Maximum Ratings.

**Table 5. Recommended Operating Conditions**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>CC</sub>	supply voltage		1.65		5.5	V
V <sub>I</sub>	input voltage		0		5.5	V
V <sub>O</sub>	output voltage	Active mode	0		V <sub>CC</sub>	V
		Power-down mode; V <sub>CC</sub> = 0 V	0		5.5	V
T <sub>amb</sub>	ambient temperature		-40		125	°C
Δt/ΔV	Input transition rise and fall rate	V <sub>CC</sub> = 1.65 V to 2.7 V			20	ns/V
		V <sub>CC</sub> = 2.7 V to 5.5 V			10	ns/V

## 9. Static Characteristics

**Table 6. Static characteristics**

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	0.65V <sub>CC</sub>			0.65V <sub>CC</sub>		V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7			1.7		V
		V <sub>CC</sub> = 2.7 V to 3.6 V	2.0			2.0		V
		V <sub>CC</sub> = 4.5 V to 5.5 V	0.7V <sub>CC</sub>			0.7V <sub>CC</sub>		V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V			0.35V <sub>CC</sub>		0.35V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V			0.7		0.7	V
		V <sub>CC</sub> = 2.7 V to 3.6 V			0.8		0.8	V
		V <sub>CC</sub> = 4.5 V to 5.5 V			0.3V <sub>CC</sub>		0.3V <sub>CC</sub>	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>						
		I <sub>O</sub> = -100µA; V <sub>CC</sub> = 1.65 V to 5.5 V	V <sub>CC</sub> - 0.1			V <sub>CC</sub> - 0.1		V
		I <sub>O</sub> = -4 mA; V <sub>CC</sub> = 1.65 V	1.2			0.95		V
		I <sub>O</sub> = -8 mA; V <sub>CC</sub> = 2.3 V	1.9			1.7		V
		I <sub>O</sub> = -12 mA; V <sub>CC</sub> = 2.7 V	2.2			1.9		V
		I <sub>O</sub> = -24 mA; V <sub>CC</sub> = 3.0 V	2.3			2.0		V
		I <sub>O</sub> = -32 mA; V <sub>CC</sub> = 4.5 V	3.8			3.4		V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>						
		I <sub>O</sub> = 100µA; V <sub>CC</sub> = 1.65 V to 5.5 V			0.10		0.10	V
		I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 1.65 V			0.45		0.70	V
		I <sub>O</sub> = 8 mA; V <sub>CC</sub> = 2.3 V			0.30		0.45	V
		I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 2.7 V			0.40		0.60	V
		I <sub>O</sub> = 24 mA; V <sub>CC</sub> = 3.0 V			0.55		0.80	V
		I <sub>O</sub> = 32 mA; V <sub>CC</sub> = 4.5 V			0.55		0.80	V
I <sub>I</sub>	Input leakage current	V <sub>I</sub> = 5.5 V or GND ; V <sub>CC</sub> = 0 V to 5.5 V		±0.1	±1		±1	µA
I <sub>OFF</sub>	power-off leakage current	V <sub>CC</sub> = 0V ; V <sub>I</sub> or V <sub>O</sub> = 5.5 V		±0.1	±2		±2	µA

## EM74LVC2G04

Dual inverter

$I_{CC}$	supply current	$V_I = 5.5V$ or GND ; $I_O = 0A$ ; $V_{CC} = 1.65V$ to $5.5V$		0.1	4		4	$\mu A$
$\Delta I_{CC}$	additional supply current	per pin ; $V_{CC} = 2.3V$ to $5.5V$ ; $V_I = V_{CC} - 0.6V$ ; $I_O = 0A$		5	500		500	$\mu A$
$C_I$	input capacitance	$V_{CC} = 3.3V$ ; $V_I = GND$ to $V_{CC}$		5				pF

[1] All typical values are measured at  $V_{CC} = 3.3V$  and  $T_{amb} = 25^\circ C$ .

## 10. Dynamic Characteristics

**Table 7. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 7.

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
$t_{pd}$	propagation delay	nA to nY; see Fig. 6 [2]						
		$V_{CC} = 1.65 V$ to $1.95 V$	2.6	7.4	12.6	2.6	12.9	ns
		$V_{CC} = 2.3 V$ to $2.7 V$	1.7	3.9	6.6	1.7	7.0	ns
		$V_{CC} = 3.0 V$ to $3.6 V$	1.4	2.5	4.0	1.4	4.2	ns
		$V_{CC} = 4.5 V$ to $5.5 V$	1.2	2.0	2.9	1.2	3.0	ns
$C_{PD}$	power dissipation capacitance	$V_I = GND$ to $V_{CC}$ ; $V_{CC} = 3.3V$ [3]		24				pF

[1] Typical values are measured at  $T_{amb} = 25^\circ C$  and  $V_{CC} = 1.8 V, 2.5 V, 3.3 V$  and  $5.0 V$  respectively.

[2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

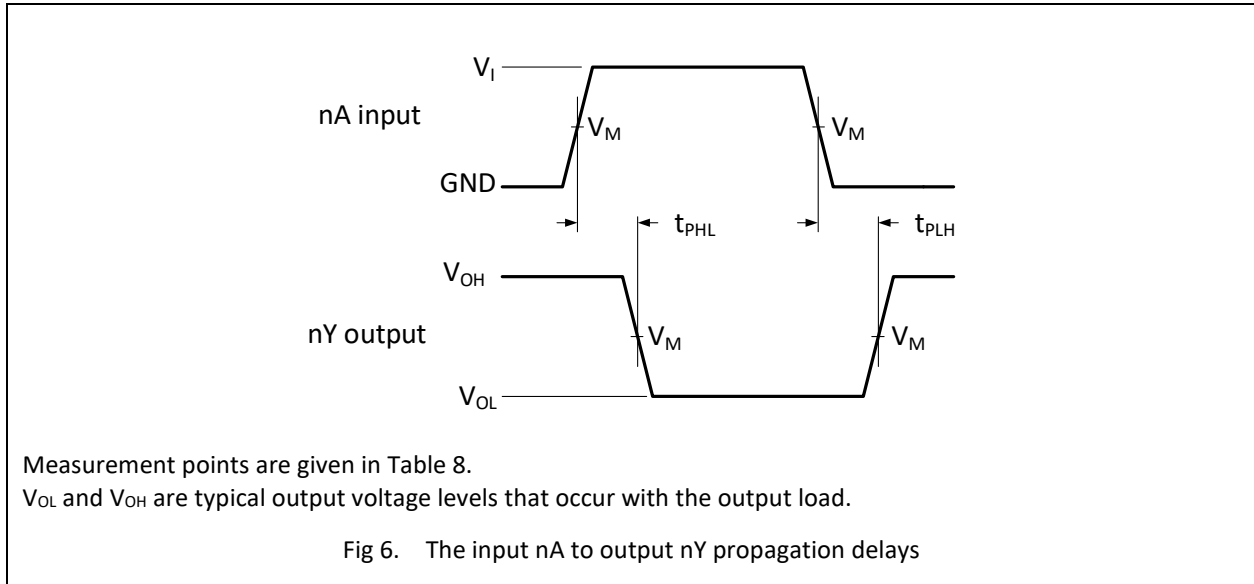
$C_L$  = output load capacitance in pF;

$V_{CC}$  = supply voltage in V;

$N$  = number of inputs switching;

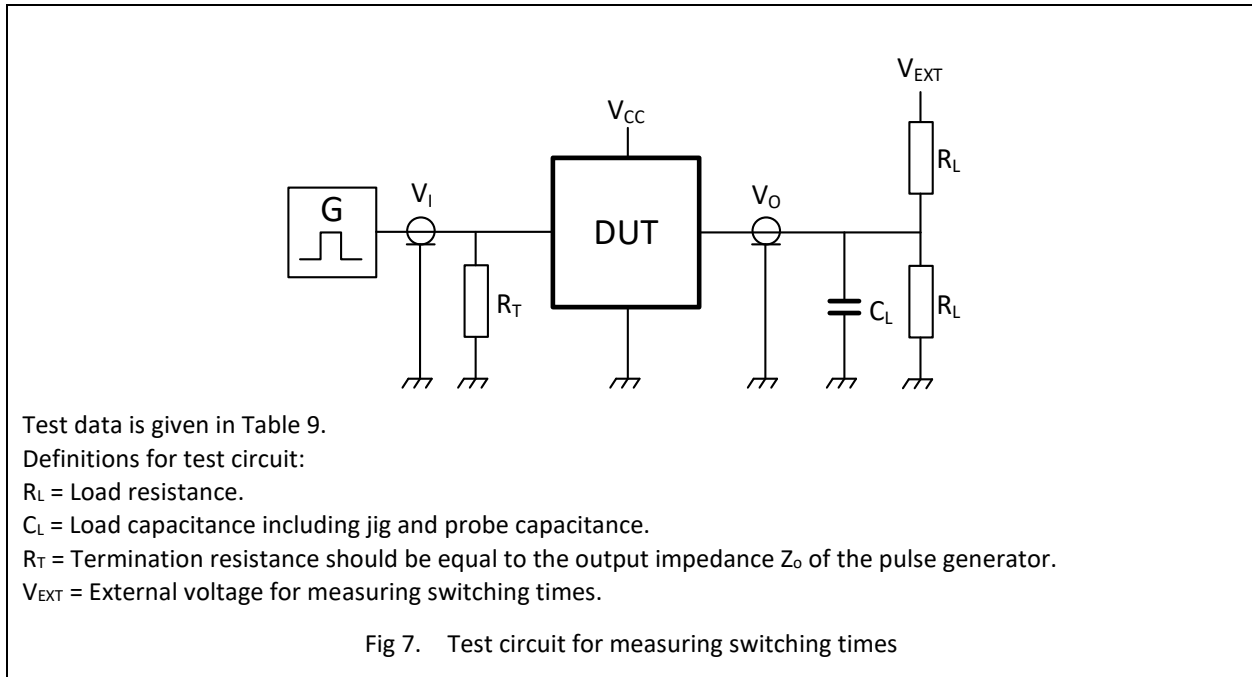
$\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

### 10.1. Waveforms and test circuit



**Table 8. Measurement points**

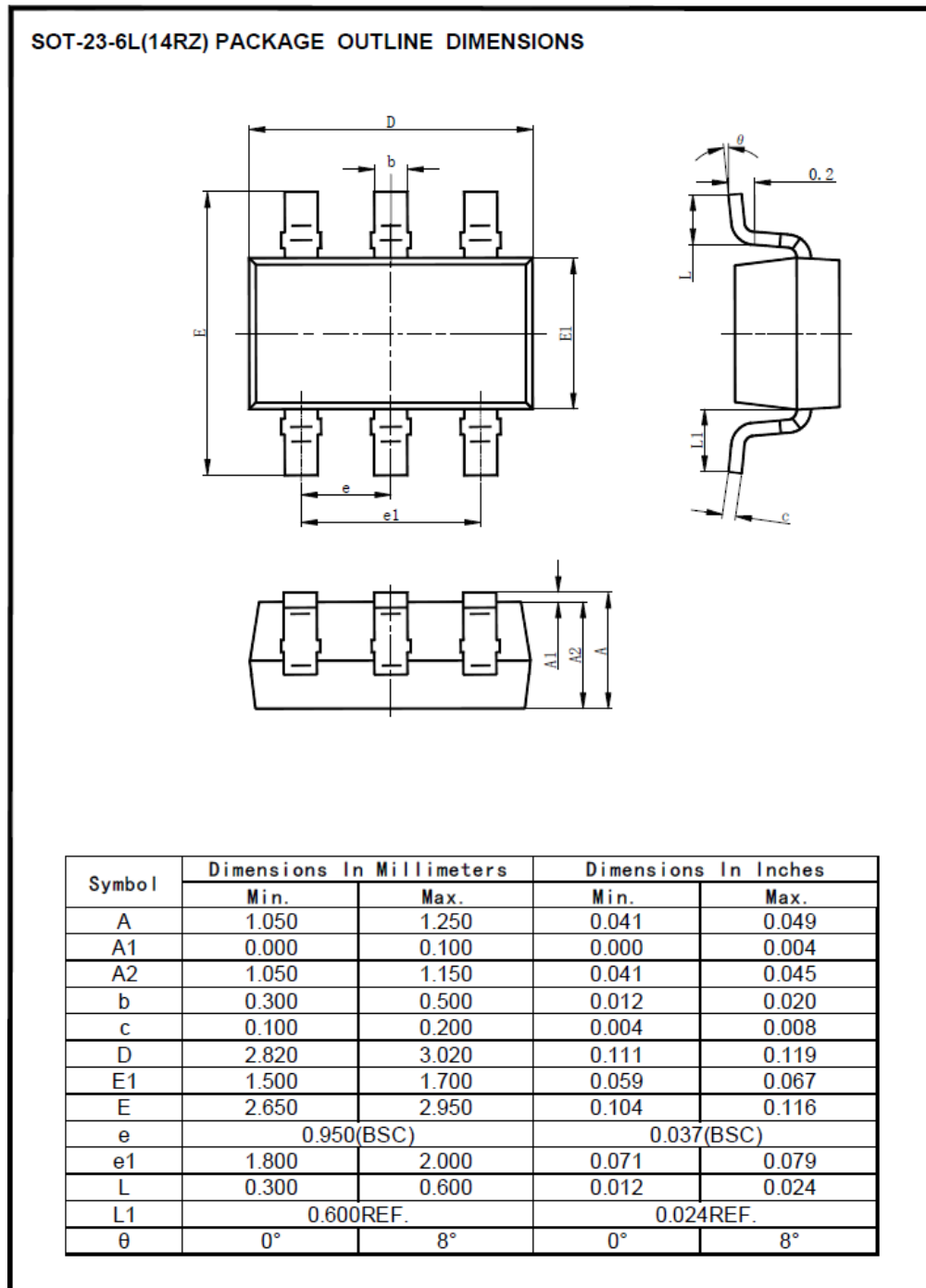
Supply voltage	Input	Output
$V_{CC}$	$V_M$	$V_M$
1.65 V to 1.95 V	$0.5V_{CC}$	$0.5V_{CC}$
2.3 V to 2.7 V	$0.5V_{CC}$	$0.5V_{CC}$
3.0 V to 3.6 V	1.5 V	1.5 V
4.5 V to 5.5 V	$0.5V_{CC}$	$0.5V_{CC}$


**Table 9. Test data**

Supply voltage	Input		Load		$V_{EXT}$
$V_{CC}$	$V_I$	$t_r = t_f$	$C_L$	$R_L$	$t_{PLH}, t_{PHL}$
1.65 V to 1.95 V	$V_{CC}$	$\leq 2.0$ ns	30 pF	1 k $\Omega$	open
2.3 V to 2.7 V	$V_{CC}$	$\leq 2.0$ ns	30 pF	500 $\Omega$	open
3.0 V to 3.6 V	3 V	$\leq 2.5$ ns	50 pF	500 $\Omega$	open
4.5 V to 5.5 V	$V_{CC}$	$\leq 2.5$ ns	50 pF	500 $\Omega$	open

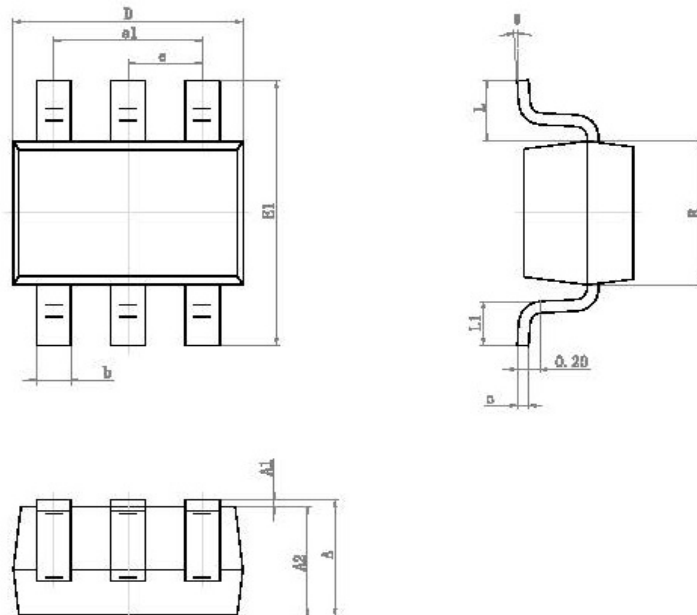
# 11. Package Outline

SOT23-6L



SOT363

**SOT-363 (16R) PACKAGE OUTLINE DIMENSIONS**

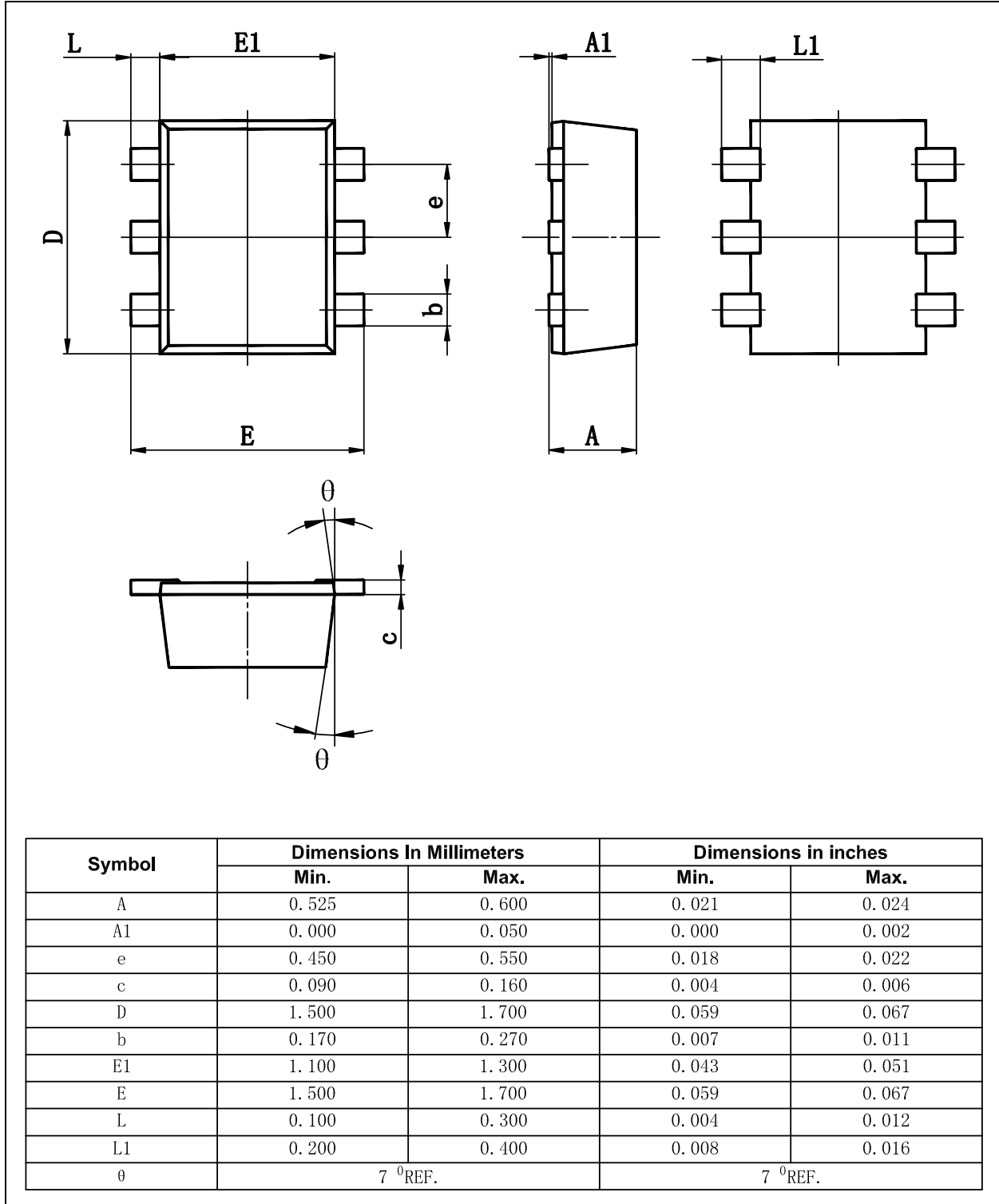


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
c	0.110	0.175	0.004	0.007
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.650 TYP.		0.026 TYP.	
e1	1.200	1.400	0.047	0.055
L	0.525 REF.		0.021 REF.	
L1	0.260	0.460	0.010	0.018
$\theta$	0°	8°	0°	8°

EM74LVC2G04

Dual inverter

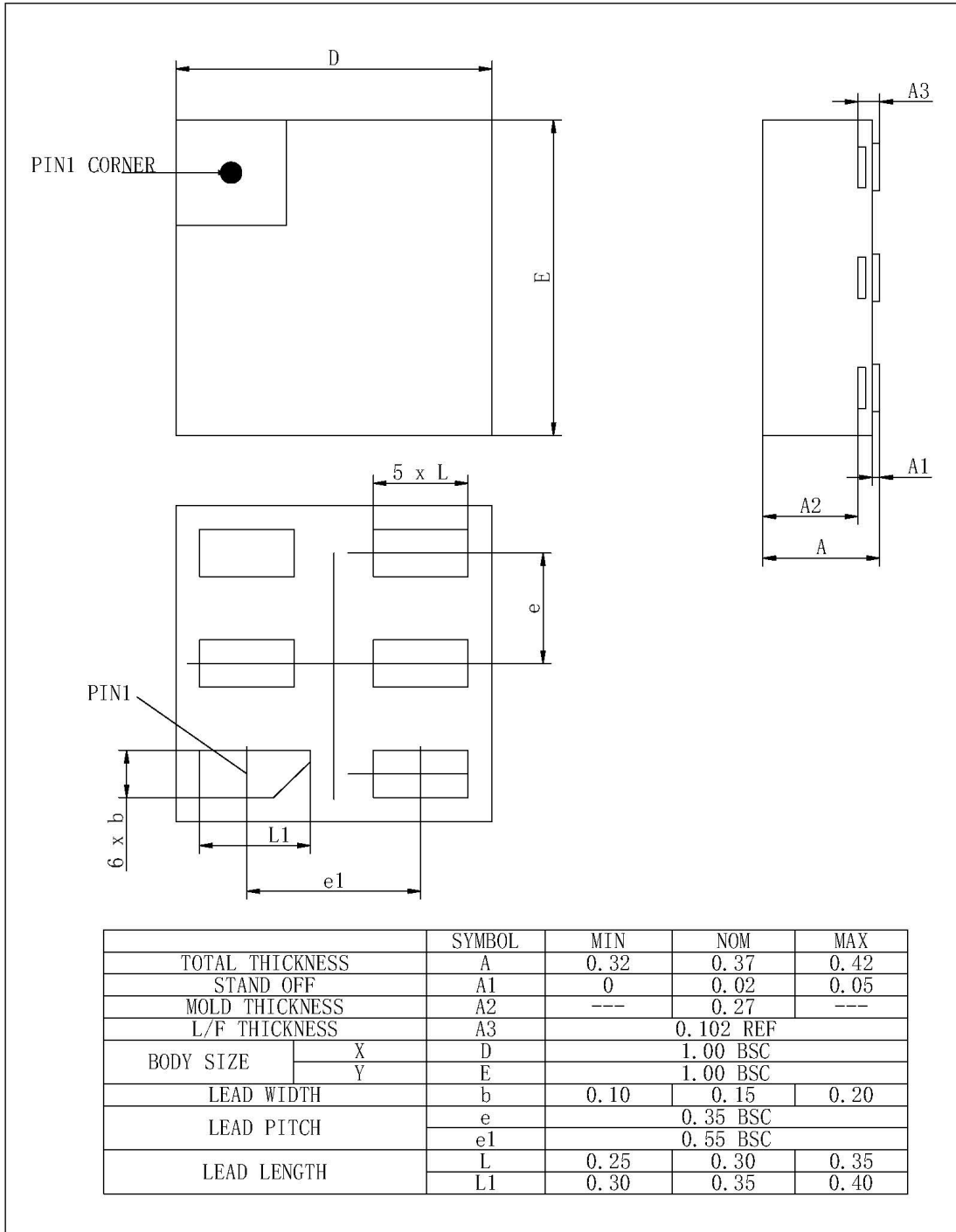
SOT563



# EM74LVC2G04

Dual inverter

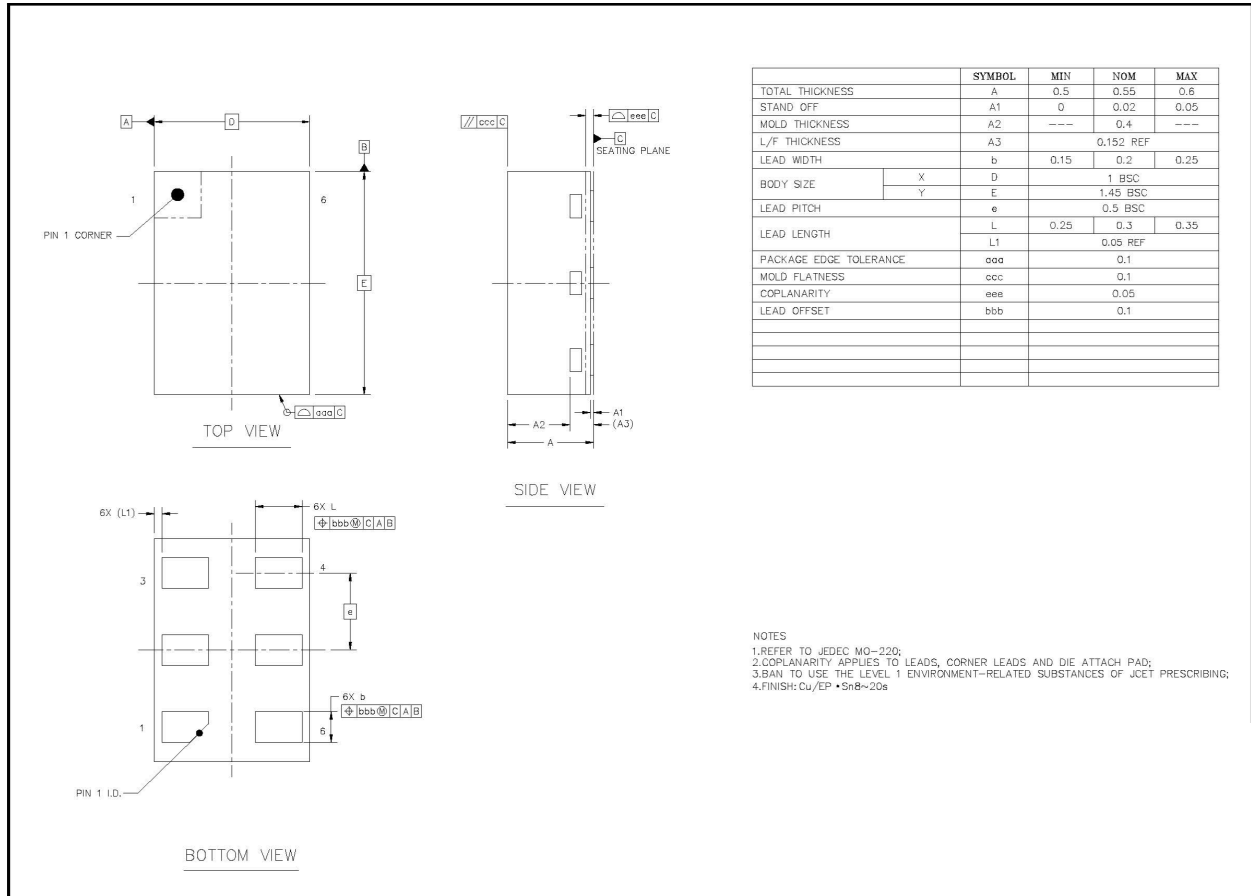
## DFN1x1-6L



# EM74LVC2G04

Dual inverter

## DFN1x1.45-6L



## 12. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

## 13. Revision History

Table 11. Revision history

Document ID	Release Date	Data sheet status	Change notice	Supersedes
EM74LVC2G04 Rev1.1	Apr 30, 2024	Product datasheet		EM74LVC2G04 Rev1.0
Modifications:	• Added SOT563 package.			
EM74LVC2G04 Rev1.0	Oct 30, 2023	Product datasheet		